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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/588,996	06/06/2000		Hisashi Ohtani	07977/220002/US3527/3777D	9311
26171	7590	12/14/2004		EXAMINER	
FISH & RI			CHUNG, DAVID Y		
1425 K STREET, N.W. 11TH FLOOR				ART UNIT	PAPER NUMBER
		20005-3500	2871		

DATE MAILED: 12/14/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Apı	olication No.	Applicant(s)				
		/588,996	OHTANI ET AL.				
Office Action Summa	Exa	aminer	Art Unit				
	Dav	vid Y. Chung	2871				
The MAILING DATE of this co	mmunication appears	on the cover sheet v	vith the correspondence addre	ss			
Period for Reply							
A SHORTENED STATUTORY PER THE MAILING DATE OF THIS COM - Extensions of time may be available under the p after SIX (6) MONTHS from the mailing date of t - If the period for reply specified above is less thar If NO period for reply is specified above, the may - Failure to reply within the set or extended period Any reply received by the Office later than three earned patent term adjustment. See 37 CFR 1.7	MUNICATION. rovisions of 37 CFR 1.136(a). his communication. thirty (30) days, a reply within timum statutory period will app for reply will, by statute, cause months after the mailing date of	In no event, however, may a the statutory minimum of th ly and will expire SIX (6) MC the application to become A	n reply be timely filed irty (30) days will be considered timely. INTHS from the mailing date of this common than the mail of the mai	unication.			
Status							
1) Responsive to communication	(s) filed on 20 Septer	mber 2004.					
2a) ☐ This action is FINAL .	2b)⊠ This action						
<u>′</u>	,		tters, prosecution as to the m	erits is			
,	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4) Claim(s) <u>1,2,4-7,11-16,20-22</u>	and 26-38 is/are pend	ling in the application	n.				
4a) Of the above claim(s)	***	= : : :					
5)⊠ Claim(s) 1 is/are allowed.							
6)⊠ Claim(s) <u>2,4-7,11-16,20-22 ar</u>	nd 26-31 is/are rejecte	ed.					
7)⊠ Claim(s) <u>32-38</u> is/are objected							
8) Claim(s) are subject to		ction requirement.					
Application Papers							
9)☐ The specification is objected to	by the Examiner.						
10)☐ The drawing(s) filed on	·	d or b) objected to	by the Examiner.				
Applicant may not request that a							
Replacement drawing sheet(s) in	•			1.121(d).			
11) The oath or declaration is obje	_	•	= : : :				
Priority under 35 U.S.C. § 119							
12)⊠ Acknowledgment is made of a a)⊠ All b)□ Some * c)□ Non		rity under 35 U.S.C.	§ 119(a)-(d) or (f).				
1. Certified copies of the p		e heen received		•			
2. Certified copies of the p			Application No. 09/008 412				
3. ☐ Copies of the certified of	•			ane			
application from the Inte	•		il received in this italional of	190			
* See the attached detailed Offic	•		nt received.				
222 I./O DINGS.IOG GOIGIOG OTHO							
Attachment(s)							
1) Notice of References Cited (PTO-892)		4) Interview	Summary (PTO-413)				
2) Notice of Draftsperson's Patent Drawing Re		Paper No	o(s)/Mail Date				
Information Disclosure Statement(s) (PTO- Paper No(s)/Mail Date	1449 or PTO/SB/08)	5) Notice of 6) Other: _	Informal Patent Application (PTO-15	o2)			

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on September 20, 2004 has been entered.

Claim Rejections - 35 USC § 102/103

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 14-16 and 20-22 rejected under 35 U.S.C. 102(e) as anticipated by or, 1. in the alternative, under 35 U.S.C. 103(a) as obvious over Sato et al. (U.S. 5,708,485).

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As to claims 14 and 20, Sato et al. discloses an active matrix display device having a structure as shown in figures 1 and 2. Note the thin film transistor 7, semiconductor thin film 10, source line 9, gate line 8, pixel electrode 6, matrix array substrate 1, opposing substrate 2, and liquid crystal layer 3. A storage capacitor 13 is formed between semiconductor thin film 10 and auxiliary line 14.

Sato et al. is silent regarding the occurrence of disclination. However, Hirata et al. provides evidence that disclination is inherent in the device of Sato et al. in regions comprising the thin film transistor and storage capacitor. Hirata et al. discloses a conventional active matrix device in figure 17 having a light blocking film 232d with an opening corresponding with an area enclosed by the dashed line. See column 18, lines 31-38. The light blocking film 232d is provided in order to prevent deterioration of the display quality occurring due to the disclination in the region outside the dashed line. Since disclination deteriorates the display quality of a wide area corresponding to the pixel electrodes 114, the opening of the light blocking film 232d is required to be reduced in size. See column 18, lines 60-66.

Because Sato et al. is substantially identical to the claimed invention and Hirata et al. presents evidence tending to show the inherency of disclination, the burden shifts to the applicant to show an unobvious difference. *In re Fitzgerald, 619 F.2d 67, 205 USPQ 594 (CCPA 1980*). See MPEP §§ 2112 - 2112.02.

As to claims 15 and 21, Sato et al. discloses a top-gate thin film transistor in figure 1.

As to claims 16 and 22, because the recitation of intended use does not result in a structural difference between the claimed invention and the prior art of Sato et al., it does not patentably distinguish the claims from Sato et al. If the prior art structure is capable of performing the intended use, the claims are considered met. See MPEP § 707.07.

2. Claim 2 rejected under 35 U.S.C. 102(e) as anticipated by or, in the alternative, under 35 U.S.C. 103(a) as obvious over Sato et al. (U.S. 5,708,485).

Sato et al. discloses an active matrix display device having a structure as shown in figures 1 and 2. Note the thin film transistor 7, semiconductor thin film 10, source line 9, gate line 8, and pixel electrode 6. A metal interconnection 12 is electrically connected to the drain of the thin film transistor and the pixel electrode 6. An insulating layer 17 is formed over the source line and a conductive light blocking film 16M is formed over insulating layer 17. The conductive light blocking film 16M and metal interconnection 12 partially overlap to form a capacitor. Sato et al. teaches that the

interlayer insulating layers 15, 17 and 18 may be formed of inorganic or organic substances. See column 7, lines 55-60.

Because the recitation of intended use does not result in a structural difference between the claimed invention and the prior art of Sato et al., it does not patentably distinguish the claims from Sato et al. If the prior art structure is capable of performing the intended use, the claims are considered met. See MPEP § 707.07.

Sato et al. is silent regarding the occurrence of disclination. However, Hirata et al. provides evidence that disclination is inherent in the device of Sato et al. in regions comprising the thin film transistor and capacitor. Hirata et al. discloses a conventional active matrix device in figure 17 having a light blocking film 232d with an opening corresponding with an area enclosed by the dashed line. See column 18, lines 31-38. The light blocking film 232d is provided in order to prevent deterioration of the display quality occurring due to the disclination in the region outside the dashed line. Since disclination deteriorates the display quality of a wide area corresponding to the pixel electrodes 114, the opening of the light blocking film 232d is required to be reduced in size. See column 18, lines 60-66.

Because Sato et al. is substantially identical to the claimed invention and Hirata et al. presents evidence tending to show the inherency of disclination, the burden shifts to the applicant to show an unobvious difference. In re Fitzgerald, 619 F.2d 67, 205 USPQ 594 (CCPA 1980). See MPEP §§ 2112 - 2112.02.

As to claim 12, Sato et al. discloses a top-gate thin film transistor in figure 1.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 4-7, 11-13 and 26-31 rejected under 35 U.S.C. 103(a) as being unpatentable over Sato et al. (U.S. 5,708,485) in further view of Ueda et al. (U.S. 5,459,596), Miyazawa (U.S. 5,781,260), Hanazawa et al. (U.S. 5,835,171), and Koseki et al. (U.S. 5,345,324).

As to claims 4, 5, 7, 11, 13, 26, 28, 29 and 31, Sato et al. discloses an active matrix display device having a structure as shown in figures 1 and 2. Note the thin film transistor 7, semiconductor thin film 10, source line 9, gate line 8, and pixel electrode 6. A first insulating layer 15 is formed over the thin film transistor. A metal interconnection 12 electrically connects the pixel electrode to the drain of the thin film transistor through a contact hole formed in insulating layer 15. The conductive light blocking film 16M and metal interconnection 12 partially overlap to form a capacitor with a second insulating layer 17 interposed between.

Because the recitation of intended use does not result in a structural difference between the claimed invention and the prior art of Sato et al., it does not patentably

distinguish the claims from Sato et al. If the prior art structure is capable of performing the intended use, the claims are considered met. See MPEP § 707.07.

Sato et al. is silent regarding the occurrence of disclination. However, Hirata et al. provides evidence that disclination is inherent in the device of Sato et al. in regions comprising the thin film transistor and capacitor. Hirata et al. discloses a conventional active matrix device in figure 17 having a light blocking film 232d with an opening corresponding with an area enclosed by the dashed line. See column 18, lines 31-38. The light blocking film 232d is provided in order to prevent deterioration of the display quality occurring due to the disclination in the region outside the dashed line. Since disclination deteriorates the display quality of a wide area corresponding to the pixel electrodes 114, the opening of the light blocking film 232d is required to be reduced in size. See column 18, lines 60-66.

Because Sato et al. is substantially identical to the claimed invention and Hirata et al. presents evidence tending to show the inherency of disclination, the burden shifts to the applicant to show an unobvious difference. In re Fitzgerald, 619 F.2d 67, 205 USPQ 594 (CCPA 1980). See MPEP §§ 2112 - 2112.02.

Sato et al. does not disclose rubbing an alignment layer in one direction from one corner of the pixel. However, this was common and conventional at the time of invention as evidenced by the disclosures of Koseki et al., Hanazawa et al., Miyazawa, and Ueda et al. See column 20, line 53 - column 21, line 4 of Ueda et al. Note in figure 3 of Miyazawa, the crossed arrows denoting the direction of the alignment treatment on the upper and lower substrates, respectively. Note in figure 7 of Hanazawa et al., the

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diagonal arrow denoting the rubbing direction of the orientation film. Note in figures 5A, 7A and 8-10 of Koseki et al., arrow 9 showing the rubbing direction. The benefits of this conventional rubbing technique included lowering manufacturing costs and producing a device with predictable behavior. Therefore, it would have been obvious to one of ordinary skill in the art at the time of invention to rub the alignment layer in one direction from one corner of the pixel because of the aforementioned benefits.

As to claims 6, 12, 27 and 30, Sato et al. discloses a top-gate thin film transistor in figure 1.

Response to Arguments

Applicant's arguments filed September 20, 2004 have been fully considered but they are not persuasive. Applicant appears to have argued against the references individually without accounting for their combined teaching. Performing a rubbing operation in a diagonal direction starting in one corner of the pixel was conventional as shown by the secondary references. Furthermore, only claims 2 and 4 explicitly require the capactor to be formed in the corner of the pixel where the rubbing operation begins, as explained in the previous office action.

Allowable Subject Matter

Claim 1 allowed.

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Claims 32-38 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to David Chung whose telephone number is (571) 272-2288. The examiner can normally be reached on Monday-Friday from 8:30 am to 5:00 pm.

RENNETH PARKER
PRIMARY EXAMINER